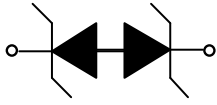


1-Line, Bi-directional, Transient Voltage Suppressor



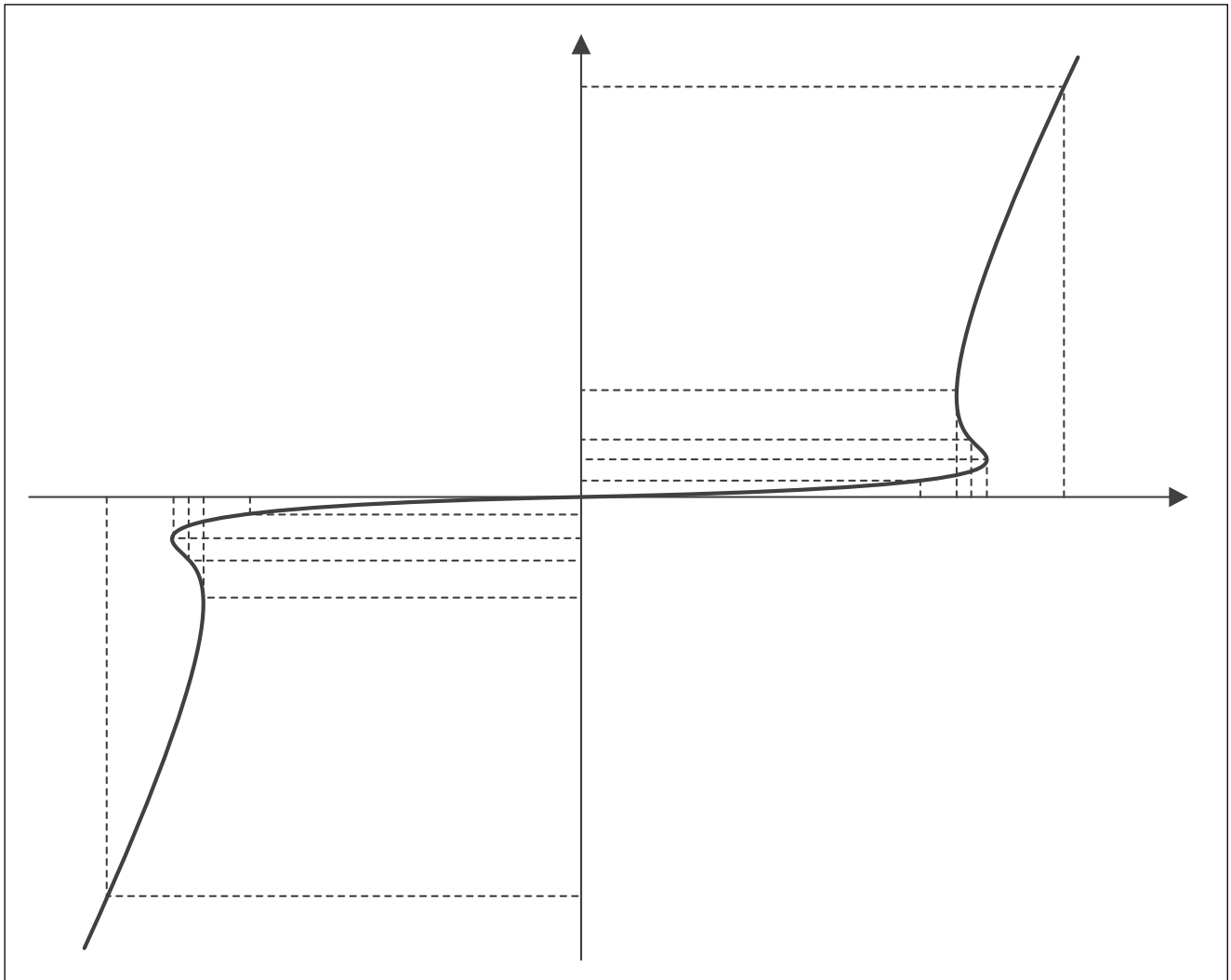
Features

- " Stand-off voltage: $\pm 7\text{V}$ Max
- " Transient protection for each line according to IEC61000-4-2(ESD): $\pm 30\text{kV}$ (contact)
IEC61000-4-4 (EFT): 40A (5/50ns)
IEC61000-4-5(surge): 6A (8/20 s)
- " Ultra-low capacitance: $C_J = 10\text{pF}$ typ
- " Low leakage current
- " Low clamping voltage: $V_{CL} = 12.0\text{V}$ typ. @ $I_{PP} = 16\text{A}$ (TLP)
- " Solid-state silicon technology

Mechanical Data

- " Package : DFN1006-2L
- " Terminals : Tin plated leads, solderable per J-STD-002 and JESD22-B102
- " Polarity: No marking on bi-directional types
- " Marking: 7A

Definitions of electrical characteristics



ESD7V0LB

Maximum Ratings

PARAMETER	SYMBOL	Rating	UNIT
Peak pulse power ($t_p = 8/20 \text{ s}$)	P_{pk}	84	W
Peak pulse current ($t_p = 8/20 \text{ s}$)	I_{PP}	6	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	KV
ESD according to IEC61000-4-2 contact discharge		± 30	KV
Junction temperature	T_J	125	$^{\circ}\text{C}$
Operating temperature	T_{OP}	-40~85	$^{\circ}\text{C}$
Storage temperature	T_{STG}	-55~150	$^{\circ}\text{C}$

Electrical Characteristics $\dot{A}T_a=25$ Unless otherwise specified $\dot{A}$

PARAMETER	Symbol	UNIT	Conditions	Min	Typ	Max
Reverse maximum working voltage	V_{RWM}	V				± 7
Reverse leakage current	I_R	nA	$V_{RWM} = 7$			100
Reverse breakdown voltage	V_{BR}	V	$I_{BR} = 1\text{mA}$	7.2		10.5
Reverse holding voltage	V_{HOLD}	V	$I_{HOLD} = 50\text{mA}$	7.2		10.5
Clamping voltage ¹⁾	V_{CL}	V	$I_{PP} = 16\text{A}$, $t_p = 100\text{ns}$		12.0	
Dynamic resistance ¹⁾	R_{DYN}				0.28	
Clamping voltage ²⁾	V_{CL}	V	$V_{ESD} = 8\text{kV}$		12.0	
Clamping voltage ³⁾	V_{CL}	V	$I_{PP} = 1\text{A}$, $t_p = 8/20 \text{ s}$		9	11
		V	$I_{PP} = 6\text{A}$, $t_p = 8/20 \text{ s}$		12	14
Junction capacitance	C_J	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$		10	13
		pF	$V_R = 2.5\text{V}$, $f = 1\text{MHz}$		8	11

(1). TLP parameter: $Z_0 = 50 \text{ } \Omega$, $t_p = 100\text{ns}$, $t_r = 2\text{ns}$, averaging window from 60ns to 80ns. R_{DYN} is calculated from 4A to 16A.

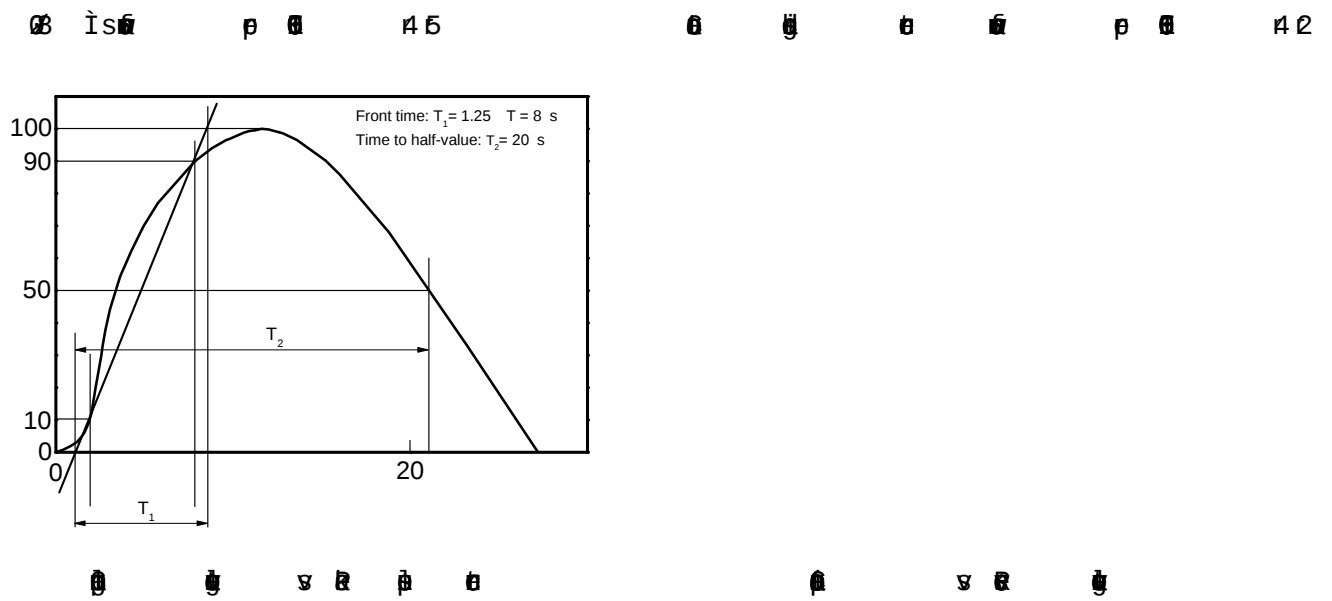
(2). Contact discharge mode, according to IEC61000-4-2.

(3). Non-repetitive current pulse, according to IEC61000-4-5.

Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(mg)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
ESD7V0LB	Approximate 0.9	10000	100000	400000	Tape&reel

vCharacteristics (Typical)



vRecommend land pattern (Unit:mm)

Notes:

This recommended land pattern is for reference purposes only.

Disclaimer

The information presented in this document is for reference only. Yangzhou Yangjie Electronic Technology Co., Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website [http:// www.21yangjie.com](http://www.21yangjie.com) , or consult your nearest Yangjie's sales office for further assistance.